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Flat-lens focusing of electrons on the surface of a topological insulator

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We propose the implementation of an electronic Veselago lens on the conducting surface of a three-dimensional topological insulator (such as Bi_2Te_3). The negative refraction needed for such a flat lens results from the sign change in the curvature of the Fermi surface, changing from a circular to a snowflake-like shape across a sufficiently large electrostatic potential step. No interband transition (as in graphene) is needed. For this reason, and because the topological insulator provides protection against backscattering, the potential step is able to focus a broad range of incident angles. We calculate the quantum interference pattern produced by a point source, generalizing the analogous optical calculation to include the effect of a noncircular Fermi surface (having a nonzero conic constant).

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I. INTRODUCTION

Ballistic electron optics relies on the analogy between the Schrödinger equation for electrons and the Helmholtz equation for classical waves to construct devices that can image the flow of electrons in high-mobility semiconductors.^{1–4} A variation in electrostatic potential is analogous to a variation in dielectric constant so that a curved gate electrode can have the refractive power of a lens—as has been demonstrated in the two-dimensional electron gas of a GaAs heterostructure.^{5,6} The focal length of this electrostatic lens depends on its curvature, diverging for a flat electrode.

Focusing of light by a flat lens is possible in media with a negative index of refraction. This so-called Veselago lens^{7,8} has a focal length proportional to the distance between lens and source, rather than fixed by the lens itself. It is also not limited by the single optical axis of a curved lens and can have a much wider aperture. Photonic crystals can provide the negative refraction needed for a flat lens,⁹ as demonstrated experimentally.^{10,11}

The electronic analog of a Veselago lens was proposed in the context of graphene¹² based on the negative refraction of an electron crossing from the conduction band into the valence band. Such interband crossing requires a p - n junction, which is highly resistive if the interface extends over more than an electron wavelength.^{13,14} It would be desirable to have a method for producing a flat lens entirely within the conduction band, in order to avoid a resistive interface. It is the purpose of this work to propose such a method, in the context of topological insulators.

Topological insulators have a conducting surface with a Dirac cone of massless, helical low-energy excitations, reminiscent of graphene.^{15,16} Indeed, scanning tunneling microscopy has shown that backscattering of the surface electrons is inhibited, as expected from conservation of helicity.^{17,18} While the large band-gap topological insulator Bi_2Se_3 has a nearly circular Dirac cone, in the smaller band-gap material Bi_2Te_3 the cone is warped in an hexagonal snowflake-like shape.^{19–23} The hexagonal warping of the Fermi surface enhances the quantum interference (Friedel) oscillations in the density of states near an impurity or potential step,^{24–27} which for a circular Fermi surface would be suppressed by conservation of helicity.²⁸

The electron focusing considered here is an altogether different, semiclassical consequence of the hexagonal warping. The flat lens is formed by a potential step on the surface of the topological insulator, sufficiently high to change the curvature of the Fermi surface from convex to concave. The sign change in the curvature leads to negative refraction and focusing, qualitatively similar to the optical Veselago lens—but quantitatively different because of the nonuniformity of the curvature (quantified by a nonzero conic constant).

In the following two sections, we derive the negative refraction and the line of focal points (caustics), as well as the diffraction pattern produced by a point source. We calculate the curvature and conic constant for the specific case of Bi_2Te_3 . We conclude in Sec. IV by comparing with the flat lens formed by a p - n junction in graphene¹² and by discussing possible experimental realizations in topological insulators.

II. NEGATIVE REFRACTION AT A POTENTIAL STEP

A. Negative refraction

Consider an electron propagating approximately along the x axis (the optical axis) and impinging at $x=0$ onto an electrostatic potential step δU produced by a gate electrode (see Fig. 1). For simplicity, we assume that the optical axis is parallel to an axis of crystallographic symmetry, such that the equienergy contours are $\pm k_y$ symmetric. (For the more general case, see Appendix.) At constant Fermi energy, the kinetic energy changes from E_i in the incident (left) region to $E_t=E_i+\delta U$ in the transmitted (right) region. The equienergy contour at the left is given locally by $\delta k_{i,x}=-\frac{1}{2}c_i k_{i,y}^2$, for a two-dimensional wave vector $\mathbf{k}_i=(k_{i,0}+\delta k_{i,x}, k_{i,y})$ approximately along the optical axis, and similarly $\delta k_{t,x}=-\frac{1}{2}c_t k_{t,y}^2$ at the right. The coefficients c_i and c_t are the curvatures of the Fermi surface for normal incidence, at the two sides of the potential step.

The velocity $\mathbf{v}=\hbar^{-1}\partial E/\partial \mathbf{k}$ is normal to the equienergy contours so that the velocities \mathbf{v}_i and \mathbf{v}_t in the left and right regions make, respectively, an angle $\theta_i=c_i k_{i,y}$ and $\theta_t=c_t k_{t,y}$ with the x axis. Conservation of transverse momentum ($k_{i,y}=k_{t,y}$) leads to the linearized Snell's law,

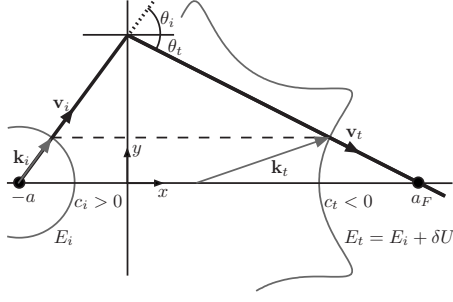


FIG. 1. Negative refraction at a potential step (height δU) where the curvature of the equienergy contours (thin curves) changes sign from $c_i > 0$ to $c_t < 0$. An electron (thick arrow) with kinetic energy E_i is incident at angle θ_i and transmitted at angle θ_t . Because the curvature changes sign, the electron is negatively refracted with $\theta_t < 0$ for $\theta_i > 0$.

$$\theta_t = (c_t/c_i)\theta_i, \quad \text{for } \theta_i, \theta_t \ll 1. \quad (2.1)$$

The inverse curvature plays the role of the refractive index in optics. Negative refraction (meaning $\theta_i\theta_t < 0$) takes place when c_i and c_t have opposite signs, as illustrated in Fig. 1.

B. Noncircular Snell's law

As we will see in the next section, to calculate the image of a point source we will need to include the first nonlinear correction to Eq. (2.1). In optics, where one has a circular equienergy contour, Snell's law $c_i \sin \theta_i = c_t \sin \theta_t$ implies the series expansion,

$$\theta_t = n_1 \theta_i + n_3 \theta_i^3 + \mathcal{O}(\theta_i^5) \quad (2.2)$$

with $n_1 = c_t/c_i$ and $n_3 = \frac{1}{6}n_1(n_1^2 - 1)$. More generally, we can write

$$n_1 = c_t/c_i, \quad n_3 = \frac{1}{6}n_1(n_1^2 - 1) + \Delta, \quad (2.3)$$

where Δ quantifies the deviation from the optical Snell's law.²⁹

The parameter Δ vanishes for a circular Fermi surface as in graphene^{12,30,31} but is nonzero for the warped Fermi surfaces of topological insulators. In order to relate Δ to the Fermi surface, we parametrize the equienergy contour using polar coordinates by $\mathbf{k} = \kappa(\phi)(\cos \phi, \sin \phi)$, where ϕ is the angle between the wave vector \mathbf{k} and the x axis and $\kappa = |\mathbf{k}|$. A subscript i or t distinguishes the parameters at the two sides of the potential step.

The noncircular Snell's law is expressed by the three equations,

$$\kappa_t(\phi_t) \sin \phi_t = \kappa_i(\phi_i) \sin \phi_i, \quad (2.4)$$

$$\tan \theta_i = \frac{\kappa_i(\phi_i) \tan \phi_i - \kappa'_i(\phi_i)}{\kappa_i(\phi_i) + \kappa'_i(\phi_i) \tan \phi_i}, \quad (2.5)$$

$$\tan \theta_t = \frac{\kappa_t(\phi_t) \tan \phi_t - \kappa'_t(\phi_t)}{\kappa_t(\phi_t) + \kappa'_t(\phi_t) \tan \phi_t}, \quad (2.6)$$

where $\kappa' = d\kappa/d\phi$. The first equation expresses the continuity of the y component of the wave vector at the interface $x=0$ while the second and third equations relate the angles θ and ϕ of velocity and wave vector (using the fact that \mathbf{v} is perpendicular to the equienergy contour). The circular Snell's law $\kappa_t \sin \theta_t = \kappa_i \sin \theta_i$ is recovered for $\kappa' = 0$, when $\theta = \phi$.

Near $\phi=0$, the equienergy contour can be parametrized in terms of the curvature c and conic constant \mathcal{K} ,

$$k_y^2 = -(2/c)\delta k_x - (1 + \mathcal{K})(\delta k_x)^2 \quad (2.7)$$

with $\delta k_x = k_x - \kappa(0)$. The noncircular Snell's law then expands to Eqs. (2.2) and (2.3) with

$$\Delta = \frac{c_t}{2c_i^3}(c_t^2 \mathcal{K}_t - c_i^2 \mathcal{K}_i). \quad (2.8)$$

C. Application to Bi₂Te₃

We apply these general considerations to the topological insulator Bi₂Te₃. On the [111] surface and close to the center of the Brillouin zone (the Γ point) the Hamiltonian can be approximated by²⁸

$$H = \hbar v k(\sigma_y \cos \phi - \sigma_x \sin \phi + \lambda^2 k^2 \sigma_z \cos 3\phi). \quad (2.9)$$

The dispersion relation in the conduction band ($E > 0$) is

$$E(\mathbf{k}) = \hbar v \sqrt{k^2 + (\lambda^2 k^3 \cos 3\phi)^2} = \hbar v \sqrt{k^2 + \lambda^4 (k_x^3 - 3k_x k_y^2)^2}. \quad (2.10)$$

The σ_i 's are Pauli matrices acting on the electron spin and ϕ denotes the angle of the wave vector \mathbf{k} with respect to the ΓK direction in the Brillouin zone (oriented along the x axis). The parameters $v \approx 4 \times 10^5$ m/s and $\lambda \approx 1$ nm were estimated by fitting to data from angularly resolved spectroscopy.^{21,22} (Additional terms quadratic in momentum can be included in the fit but these do not qualitatively change the dispersion.)

The curvature $c(E)$ of the equienergy contour in the ΓK direction is given by

$$c(E) = \lambda \frac{1 - 6\kappa^4}{\kappa + 3\kappa^5} \quad (2.11)$$

with $\kappa^2 = \xi_+^{1/3} - \xi_-^{1/3}$ defined in terms of

$$\xi_{\pm} = \frac{1}{6\hbar^2 v^2} \left(\sqrt{\frac{4}{3} \hbar^4 v^4 + 9\lambda^4 E^4} \pm 3\lambda^2 E^2 \right). \quad (2.12)$$

The quantity $\kappa/\lambda = \kappa(0)$ equals $|\mathbf{k}|$ at $\phi=0$.

The energy dependence of the curvature is plotted in Fig. 2. As discovered by Fu,²⁸ the curvature changes sign when $\kappa_c^4 = 1/6$, which corresponds to an energy $E_c = 6^{-3/4} \sqrt{7} \hbar v / \lambda \approx 0.2$ eV and a wave vector $k_c = \kappa_c / \lambda \approx 0.6$ nm⁻¹. At the same point the conic constant

$$\mathcal{K}(E) = \frac{3\kappa^4(35 - 60\kappa^4 + 72\kappa^8)}{(1 - 6\kappa^4)^3} \quad (2.13)$$

diverges and thereby changes sign, cf. Fig. 3.

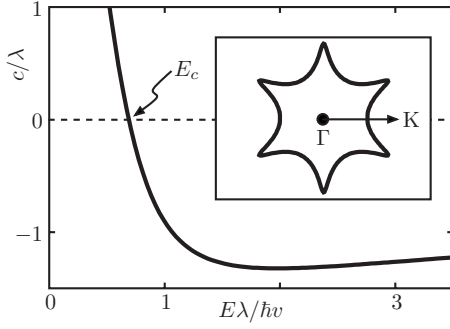


FIG. 2. Curvature $c(E)$ of the equienergy contour in the ΓK direction, calculated from Eq. (2.11). The shape changes from convex to concave at energy E_c . The maximally negative curvature is $c \approx -1.3\lambda$ for $E \approx 2\hbar v/\lambda$, where the equienergy contour has the snowflakelike shape shown in the inset.

III. CAUSTICS FROM A POINT SOURCE

A. Focusing of classical trajectories

Because of the negative refraction, diverging trajectories become converging at the potential step and then cross at a focal point (see Fig. 4). If a point source is placed at $(-a, 0)$, a distance a from the interface at $x=0$, then the trajectory for an electron incident at an angle θ_i and transmitted at an angle θ_t is parametrized by

$$y(x; \theta_i) = \begin{cases} (a+x)\tan \theta_i, & \text{for } x < 0, \\ a \tan \theta_i + x \tan \theta_t, & \text{for } x > 0. \end{cases} \quad (3.1)$$

On the optical axis $y, \theta_i, \theta_t \rightarrow 0$ we obtain the focal point $(a_F, 0)$ with

$$a_F = -a/n_1 = -\frac{c_i}{c_t}a, \quad (3.2)$$

proportional to the ratio of the two curvatures. As in the optical Veselago lens,^{32,33} the focal point is displaced from the optical axis as we increase the angle of incidence, so that the point $(a_F, 0)$ is the cusp on a curve of focal points. This caustic curve (called an *astroid*³⁴) is visible in Fig. 4 as the envelope of the refracted trajectories.

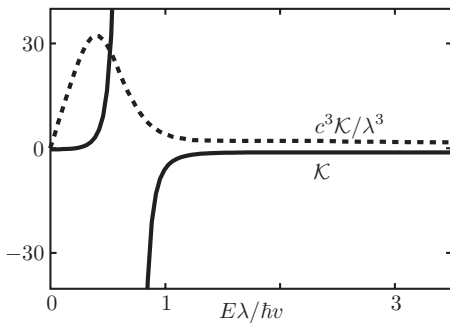


FIG. 3. Plot of the conic constant \mathcal{K} (solid line) as well as the combination $c^3\mathcal{K}/\lambda^3$ [appearing in the noncircular Snell's law, Eq. (2.8)] (dashed line), both as a function of the energy E . The divergence of \mathcal{K} is at the energy E_c where the curvature vanishes.

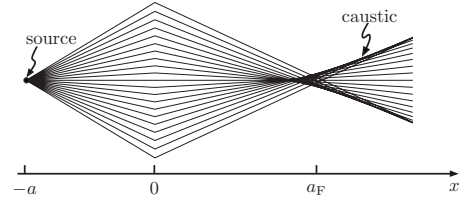


FIG. 4. Classical trajectories refracted at a potential step at $x=0$ with the cusp caustic indicated.

The caustic curve near $(a_F, 0)$ is obtained from Eq. (3.1) and the nonlinear Snell's law, Eq. (2.2), by demanding that $\partial y / \partial \theta_i = 0$. We find

$$\alpha(y/a)^2 = (x/a_F - 1)^3 \quad (3.3)$$

with the opening rate of the cusp governed by the parameter

$$\alpha = \frac{27}{8} [1 - (c_t/c_i)^2 - 2(c_t/c_i)\Delta]. \quad (3.4)$$

For $\Delta=0$, so for a circular Fermi surface, this agrees with Refs. 12 and 33. Depending on the sign of α , the cusp points away from the potential step (for $\alpha > 0$) or toward the potential step (for $\alpha < 0$). For $\alpha=0$ higher than third-order terms in the expansion, Eq. (2.2), have to be included in order to obtain the caustic curve.

B. Quantum interference near the focal point

The diffraction pattern near a cusp caustic has a universal functional form (Pearcey integral),^{35,36} but the parameters governing that function are modified for noncircular equienergy contours. We calculate the wave function Ψ at a point $\mathbf{r}=(x, y)$ near the cusp by summing over partial waves Ψ_{y_0} from points $\mathbf{r}_0=(0, y_0)$ along the potential step [excited by a point source at $\mathbf{r}_{\text{source}}=(-a, 0)$]. In the far-field approximation,³⁷ for a and a_F large compared to the wave length, the partial waves have the simple form

$$\Psi_{y_0} = \begin{pmatrix} u_{y_0} \\ v_{y_0} \end{pmatrix} A_{y_0} e^{i\Phi_{y_0}}, \quad (3.5)$$

$$\Phi_{y_0} = \mathbf{k}_i \cdot (\mathbf{r}_0 - \mathbf{r}_{\text{source}}) + \mathbf{k}_t \cdot (\mathbf{r} - \mathbf{r}_0). \quad (3.6)$$

The amplitude A_{y_0} and spinor components u_{y_0}, v_{y_0} vary slowly as y_0 is varied on the scale of the wavelength, so we fix their values at A_0, u_0, v_0 and retain only the y_0 dependence of the phase Φ_{y_0} .

In the optical case, the wave vectors \mathbf{k}_i and \mathbf{k}_t at the two sides of the interface point in the direction of the velocity and hence are parallel to the rays $\mathbf{r}_0 - \mathbf{r}_{\text{source}}$ and $\mathbf{r} - \mathbf{r}_0$. For a noncircular Fermi surface this is no longer true and we have to take into account the difference between the angles ϕ_i, ϕ_t , and $\theta_i = \arctan(y_0/a)$ and $\theta_t = \arctan[(y - y_0)/x]$ which the wave vectors and the rays make with the x axis. The relation between ϕ and θ is expressed by Eqs. (2.5) and (2.6), in terms of the radial parameter $\kappa(\phi) = |\mathbf{k}|$ of the equienergy contour.

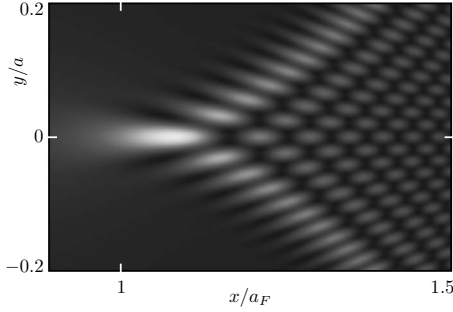


FIG. 5. Grayscale plot of the current density $j(\mathbf{r})$ as a function of position $\mathbf{r}=(x,y)$ near the focal point $(a_F, 0)$ for a source located at $(-a, 0)$, calculated from Eqs. (3.7) and (3.8) for $\alpha=1$ and $a/c_i=100$. Lighter shades of gray indicate higher current densities. The cusp caustic starting at the focal point is decorated by oscillations on the scale of the wavelength.

We expand Φ_{y_0} in a power series in y_0 . Near the cusp caustic, Eq. (3.3), $y/a = \mathcal{O}(y_0/a)^3$ while $x/a_F - 1 = \mathcal{O}(y_0/a_F)^2$. To fourth order in y_0 we find

$$\Phi_{y_0} = \kappa_i(0)a + \kappa_t(0)x - \frac{yy_0}{c_i a_F} - \frac{(x - a_F)y_0^2}{2c_i a_F^2} + \frac{\alpha y_0^4}{27c_i a_F a^2} \quad (3.7)$$

with α given by Eq. (3.4). One readily checks that the stationary phase equations $\partial\Phi_{y_0}/\partial y_0 = 0 = \partial^2\Phi_{y_0}/\partial y_0^2$ give the caustic curve, Eq. (3.3). (These equations correspond to the geometric optics limit $c_i \rightarrow 0$ of vanishing wavelength.)

The current density $j(\mathbf{r})$ follows upon integration over y_0 ,

$$j(\mathbf{r}) = j_0 \left| \int_{-\infty}^{\infty} dy_0 e^{i\Phi_{y_0}} \right|^2 \quad (3.8)$$

with j_0 a constant proportional to the product of the injection rate at the source and the transmission probability T through the potential step. By rescaling the integration variable $y_0 \rightarrow ay'_0$, we see that the current density, Eq. (3.8), as a function of x/a_F and y/a depends only on the two parameters α and a/c_i . Figure 5 is a plot of this current density, showing the characteristic interference pattern of a cusp caustic.

C. Focusing by a flat lens

The flat lens in Fig. 6 is formed by the potential profile $U(x) = \delta U$ for $0 < x < L$, $U(x) = 0$ otherwise. We denote the

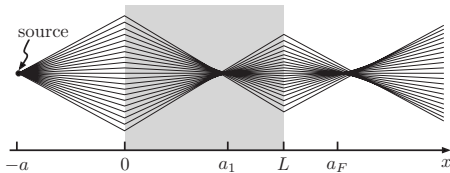


FIG. 6. Flat lens with two potential steps (upward at $x=0$ and downward at $x=L$) and two cusp caustics (at $x=a_1$ and $x=a_F$).

Fermi-surface curvatures (of opposite sign) inside the lens ($0 < x < L$) by c_{lens} and outside ($x < 0, x > L$) by c_0 . Negative refraction at the two potential steps at $x=0$ and $x=L$ focuses a source at $x=-a$ on the optical axis ($y=0$) first onto the point $a_1 = -(c_0/c_{\text{lens}})a$ inside the lens and then onto the point

$$a_F = (1 - c_{\text{lens}}/c_0)L - a \quad (3.9)$$

outside the lens (provided it is sufficiently thick, $|c_{\text{lens}}L| > |c_0a|$).

The classical trajectories are now parametrized by

$$y(x; \theta_i) = \begin{cases} (a+x)\tan \theta_i, & \text{for } x < 0, \\ a \tan \theta_i + x \tan \theta_t, & \text{for } 0 < x < L, \\ (a+x-L)\tan \theta_t + L \tan \theta_i, & \text{for } x > L. \end{cases} \quad (3.10)$$

The relation between θ_t and θ_i is still given by Eq. (2.2) with

$$n_1 = c_{\text{lens}}/c_0, \quad n_3 = \frac{1}{6}n_1(n_1^2 - 1) + \Delta. \quad (3.11)$$

The cusp caustic near $(a_F, 0)$ has the form

$$\beta(y/a)^2 = (x/a_F - 1)^3, \quad (3.12)$$

as in Eq. (3.3) but with a different parameter

$$\beta = \frac{27}{8} \frac{La^2}{a_F^3} \frac{c_{\text{lens}}}{c_0} [1 - (c_{\text{lens}}/c_0)^2 - 2(c_0/c_{\text{lens}})\Delta]. \quad (3.13)$$

Notice that α and β have the opposite sign (because of the factor $c_{\text{lens}}/c_0 < 0$) so that the cusps inside and outside the lens point in opposite directions (as visible in Fig. 6).

The flat-lens diffraction pattern near the caustic is given by the same Pearcey integral, Eqs. (3.7) and (3.8), as for a single interface but with different coefficients,

$$j(\mathbf{r}) = j_0 \left| \int_{-\infty}^{\infty} dy_0 \exp \left[-\frac{yy_0}{c_0 a_F} - \frac{(x - a_F)y_0^2}{2c_0 a_F^2} + \frac{\beta y_0^4}{27c_0 a_F a^2} \right] \right|^2. \quad (3.14)$$

Thus, the interference pattern that can be observed near a_F looks similar to Fig. 5.

IV. DISCUSSION

A. Intraband versus interband negative refraction

The Veselago lens at a p - n junction in graphene¹² uses *interband* scattering to achieve negative refraction. In contrast, the mechanism considered here is *intraband*, operating entirely within the conduction band. The p - n junction has one special feature which our setup lacks, which is the possibility to use electron-hole symmetry to collapse the caustic curve onto a single focal point (when $c_t = -c_i$). In our setup the Fermi surfaces at the two sides of the potential step are not related by any symmetry relation, so in general the two Fermi-surface curvatures c_t and c_i will be different in magnitude.

The main advantage of an intraband over an interband mechanism for negative refraction is that the transmission probability T can be much higher. Typically, the width d of the potential step will be large compared to the Fermi wavelength $\lambda_F = 2\pi/k_F$. Intraband transmission is then realized with unit probability, up to exponentially small backscattering corrections: $T = 1 - \mathcal{O}(e^{-k_F d})$. Interband transmission, in contrast, has $T \approx \exp(-k_F d \sin^2 \theta_i)$, so it is exponentially suppressed for angles further than $\sqrt{\lambda_F/d}$ from normal incidence.¹⁴

B. Experimental realization

Realization of the intraband flat lens proposed here, requires firstly a topological insulator with sufficiently long mean-free paths to ensure ballistic motion of the electrons from source to focus. Sufficiently pure single crystals should make this possible.

Secondly, and more specifically, the curvature of the Fermi surface should be tunable from positive to negative values by a gate voltage. From spectroscopic data²² for Sn-doped Bi_2Te_3 we would estimate that a potential step $\delta U \approx -0.1$ eV would produce a positive curvature inside a narrow strip and a negative curvature outside (as in Fig. 6). The strip itself would also allow for bulk conduction because in Bi_2Te_3 a positively curved Dirac cone of surface states overlaps with bulk states. Since the regions outside the lens have only surface conduction, we do not expect the bulk states inside the lens to spoil the focusing.

We deduce characteristic parameter values for this concrete example from Ref. 28. Outside the narrow strip, the Fermi energy (with $E_F = 0.28$ eV) is negatively curved. From Eq. (2.12) (using the aforementioned experimental values $v = 5 \times 10^5$ m/s and $\lambda = 1$ nm), we obtain the dimensionless wave number $\kappa_0 = 0.92$ which in turn determines the curvature $c_0 = -1.1$ nm and the conic constant $\mathcal{K}_0 = -1.8$ in the ungated region. Inside the narrow strip, we assume (for concreteness) a potential step $\delta U = -0.13$ eV which results in an electrochemical potential $E_{\text{lens}} = 0.15$ eV ($\kappa_{\text{lens}} = 0.60$). Inserting this value in Eqs. (2.11) and (2.13), we obtain $c_{\text{lens}} = 0.28$ nm and $\mathcal{K}_{\text{lens}} = 850$. The position of the cusp and the parameters of the caustic now follow easily using the result of Sec. III C, as a function of the particular values of a and L in the experimental setup. Specifically, we find $a_F = 1.3$ $L - a$ for $L > 3.9a$, $\Delta = -7.2$, and $\beta = 48La^2/a_F^3$.

A point source can be created, for example, using the “needle-anvil” technique developed for point-contact spectroscopy,³⁸ or alternatively using a scanning tunneling microscope (STM). For the spatially resolved detection of the current density distribution an STM tip is most convenient. Such a setup would provide a sensitive probe of the nonspherical Fermi surface of a topological insulator, in a similar way as has recently been proposed for metals.³⁹

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APPENDIX: SHEARED CAUSTIC CURVE FOR TILTED POTENTIAL STEP

In the main text we have assumed for simplicity that the potential step is perpendicular to the ΓK direction in Fig. 2. Then only odd powers of θ_i appear in the expansion, Eq. (2.2). If the potential step is tilted relative to this crystallographic axis, then the cusp caustic persists but in a distorted form, as we now derive.

Including also even powers of θ_i in Eq. (2.2) one would have the expansion,

$$\theta_i = n'_0 + n'_1 \theta_i + n'_2 \theta_i^2 + n'_3 \theta_i^3 + \mathcal{O}(\theta_i^4). \quad (\text{A1})$$

By rotating the coordinate axis, we can set $n'_0 = 0$. The expressions simplify if we expand in powers of $\tan \theta_i$,

$$\tan \theta_i = m_1 \tan \theta_i + m_2 \tan^2 \theta_i + m_3 \tan^3 \theta_i + \mathcal{O}(\tan^4 \theta_i). \quad (\text{A2})$$

From Eq. (3.1), demanding $\partial y / \partial \theta_i = 0$, we obtain the implicit caustic equation

$$\begin{pmatrix} x \\ y \end{pmatrix} = a(m_1 + 2m_2 \tan \theta_i + 3m_3 \tan^2 \theta_i)^{-1} \times \begin{pmatrix} -1 \\ (m_2 + 2m_3 \tan \theta_i) \tan^2 \theta_i \end{pmatrix}. \quad (\text{A3})$$

The cusp of the caustic is given by the condition $\partial x / \partial \theta_i = 0$. It is at $\tan \theta_{i0} = -m_2/3m_3$. In order to remain in the region of validity of the expansion, Eq. (A1), we assume that $|m_2| \ll |m_3|$ so that the tilt remains small. Then the cusp is located at

$$\begin{pmatrix} x_0 \\ y_0 \end{pmatrix} = \begin{pmatrix} -a/m_1 \\ 0 \end{pmatrix}. \quad (\text{A4})$$

We now expand Eq. (A3) near $\tan \theta_i = \tan \theta_{i0}$ to third order in $\delta = \tan \theta_i - \tan \theta_{i0}$,

$$\begin{pmatrix} x - x_0 \\ y - y_0 \end{pmatrix} = am_3 m_1^{-1} \begin{pmatrix} 3m_1 \delta^2 \\ -m_2 m_3^{-1} \delta^2 + 2\delta^3 \end{pmatrix}. \quad (\text{A5})$$

Eliminating δ yields the caustic curve

$$\gamma[y - y_0 + \epsilon(x - x_0)]^2 = (x - x_0)^3 \quad (\text{A6})$$

with coefficients $\gamma = 27am_3/4m_1^4$ and $\epsilon = m_1 m_2/3m_3$. Equation (A6) has the general form of a sheared cusp caustic from catastrophe theory.⁴⁰

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